

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S77	1	10/797876	US-PGPUB; USPAT	OR	ON	2009/05/20 17:40
S78	2	("20030218189").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/05/20 17:46
S79	162	((silicon adj1 germanium) SiGe) same ((dielectric k insulator) with high) same anneal\$3	US-PGPUB; USPAT	OR	ON	2009/06/04 08:15
S81	3	S79 and S80	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/06/04 08:16
S80	28	(US-20060086977-\$ or US-20060071275-\$ or US-20050250302-\$ or US-20050242406-\$ or US-20050199877-\$ or US-20050181621-\$ or US-20050099839-\$ or US-20050139872-\$ or US-20050064322-\$ or US-20050045969-\$ or US-20050070070-\$ or US-20040169177-\$ or US-20040227154-\$ or US-20040157455-\$ or US-20030010980-\$ or US-20030098479-\$ or US-20020014625-\$ or US-20040099903-\$ or US-20050130424-\$ or US-20050079691-\$ or US-20020115252-\$ or US-20020050608-\$ or US-20020048910-\$).did. or (US-7034337-\$ or US-6423632-\$ or US-5403434-\$ or US-6825102-\$).did. or (US-20020174826-\$).did.	US-PGPUB; USPAT; DERWENT	OR	ON	2009/06/04 08:16
S84	70	S83 and S82	US-PGPUB; USPAT	OR	ON	2009/06/04 08:20
S83	47017	((silicon adj1 germanium) SiGe)	US-PGPUB; USPAT	OR	ON	2009/06/04 08:20

S82	231	anneal\$3 near5 after near5 ((dielectric k insulator) with high)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/06/04 08:20
S85	11	("20030008521"   "20060065930"   "6410471"   "6503861"   "6501121"   "6518634"   "6528377"   "6610548"   "6638872"   "7015121"   "7119385").PN.	US-PGPUB; USPAT	OR	ON	2009/06/04 08:59
S86	19	anneal\$3 near5 after near5 ((dielectric k insulator) with high) near5 oxide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/06/04 09:06
S87	16	interfacial same characteristics same strained	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/06/04 09:10
S89	342712	anneal\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/06/04 09:45
S88	61	sige near2 surface near2 channel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/06/04 09:45
S93	51	S92 and S90 and S89	US-PGPUB; USPAT	OR	ON	2009/06/04 09:46
S92	88890	((dielectric k insulator) near3 high)	US-PGPUB; USPAT	OR	ON	2009/06/04 09:46
S91	188934	((dielectric k insulator) with high)	US-PGPUB; USPAT	OR	ON	2009/06/04 09:46
S90	69	((silicon adj1 germanium) SiGe) near2 surface near2 channel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/06/04 09:46
S99	39	((RAYMOND) near2 (JOE)). INV.	US-PGPUB; USPAT; USOCR	OR	ON	2009/06/04 11:08
S98	18	((SEUNGHO) near2 (OH)). INV.	US-PGPUB; USPAT; USOCR	OR	ON	2009/06/04 11:08
S97	17	((ALLEN) near2 (LEITH)). INV.	US-PGPUB; USPAT; USOCR	OR	ON	2009/06/04 11:08
S96	28	((SANJEEV) near2 (KAUSHAL)).INV.	US-PGPUB; USPAT; USOCR	OR	ON	2009/06/04 11:08
S95	175	((PRADIP) near2 (ROY)). INV.	US-PGPUB; USPAT; USOCR	OR	ON	2009/06/04 11:08

S94	44	((ANTHONY) near2 (DIP)). INV.	US-PGPUB; USPAT; USOCR	OR	ON	2009/06/04 11:08
S101	1	S100 and S82	US-PGPUB; USPAT	OR	ON	2009/06/04 11:09
S100	272	S95 S96 S97 S98 S99 S94	US-PGPUB; USPAT	OR	ON	2009/06/04 11:09
S102	92	S100 and S89	US-PGPUB; USPAT	OR	ON	2009/06/04 11:10
L2	3077	(438/285,287,785).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/06/05 09:52
L1	616	(257/E21.091,E21.092). CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/06/05 09:52

**6/ 5/ 2009 9:53:06 AM**

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